



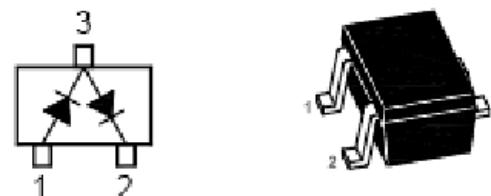
Features

Fast switching device ($T_{rr} < 4.0\text{ns}$)
 Surface device type mounting
 Moisture sensitivity level 1
 Matte Tin(Sn) lead finish with Nickel(Ni) underplate
 Pb free version and RoHS compliant
 Green compound (Halogen free) with suffix "G" on
 packing code and prefix "G" on date code

Mechanical Data

Case : Flat lead SOT-323 small outline plastic package
 Terminal : Matte tin plated, solderable
 per MIL-STD-202, Method 208 guaranteed
 High temperature soldering guaranteed: $260^\circ\text{C}/\text{S}$
 Polarity : Indicated by cathode band
 Weight : 5 mg

Pin Configuration



Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$)

Parameter	Symbol	Value	Units
Peak Repetitive Reverse Voltage	V_{RRM}	85	V
Reverse Voltage	V_R	75	V
Continuous Forward Current	I_F	150	mA
Double Diode Load	I_F	130	
Repetitive Peak Forward Current	I_{FRM}	500	mA
Peak Forward Surge Current ($t_p = 10\text{ms}$)	I_{FSM}	4	A
at $t = 1\mu\text{s}$		1	
at $t = 1\text{ms}$		0.5	
Total Power Dissipation	P_{tot}	200	mW
Thermal Resistance from Junction Ambient	R_{thJA}	625	$^\circ\text{C}/\text{W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_A = 25^\circ\text{C}$

Parameter	Symbol	Max.	Units
Forward Voltage at $I_F = 1\text{ mA}$	V_F	0.715	V
at $I_F = 10\text{ mA}$		0.855	
at $I_F = 50\text{ mA}$		1	
at $I_F = 150\text{ mA}$		1.25	
Reverse Current at $V_R = 25\text{ V}$	I_R	30	nA
at $V_R = 75\text{ V}$		1	uA
at $V_R = 25\text{ V}, T_J = 150^\circ\text{C}$		30	uA
at $V_R = 75\text{ V}, T_J = 150^\circ\text{C}$		50	uA
Total Capacitance at $V_R = 0\text{ V}, f = 1\text{ MHz}$	C_d	1.5	pF
Reverse Recovery Time at $I_F = I_R = 10\text{ mA}, I_{rr} = 0.1 \times I_R, R_L = 100\Omega$	t_{rr}	4	ns

Small Signal Product

Fig. 1 Forward Current Derating Curve

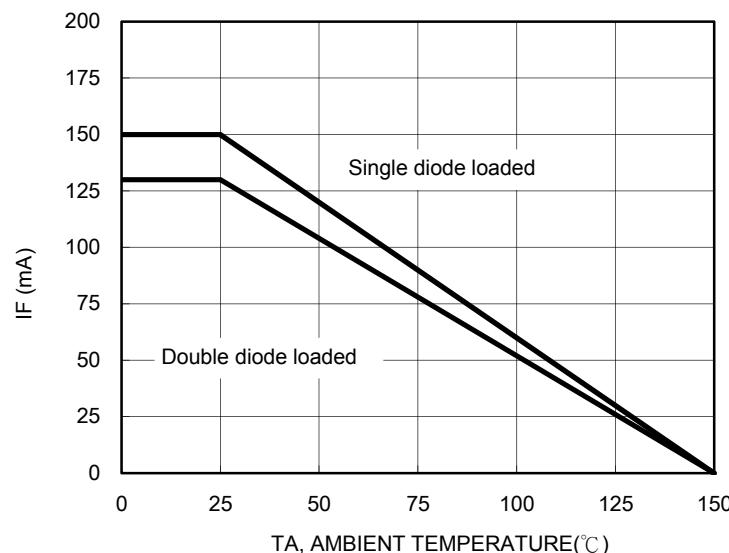


Fig. 2 Forward Characteristics

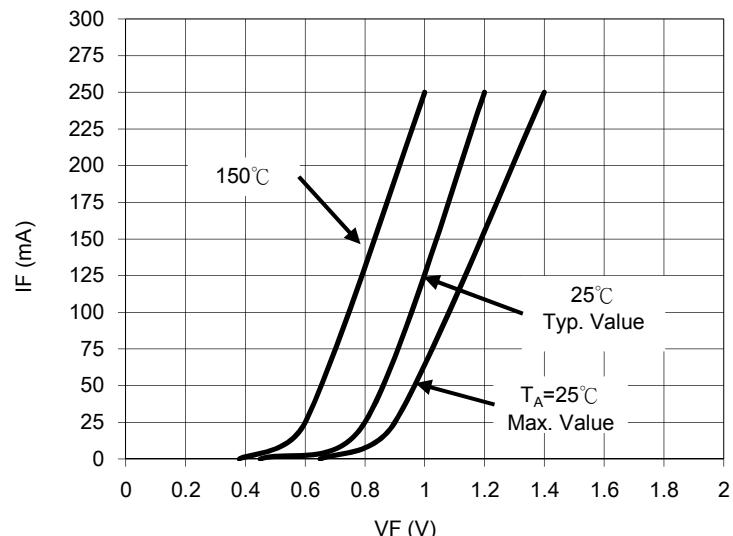


Fig. 3 Maximum Non-repetitive Peak Forward Surge Current

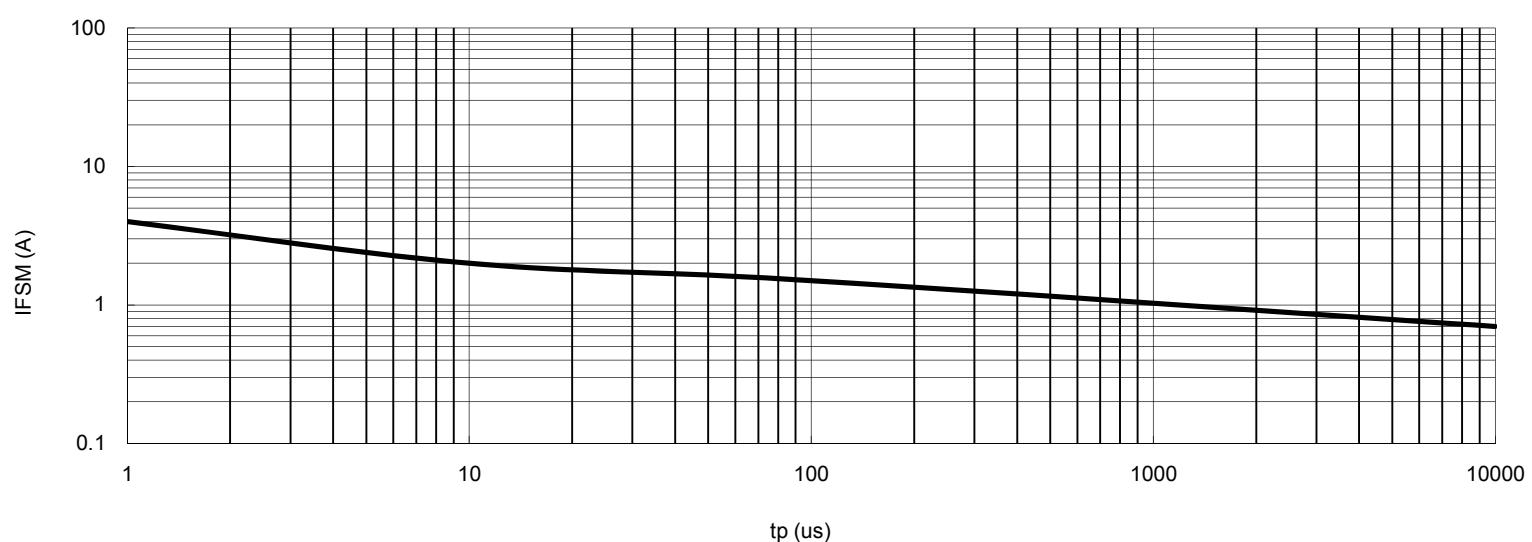


Fig. 4 Typical Reverse Characteristics

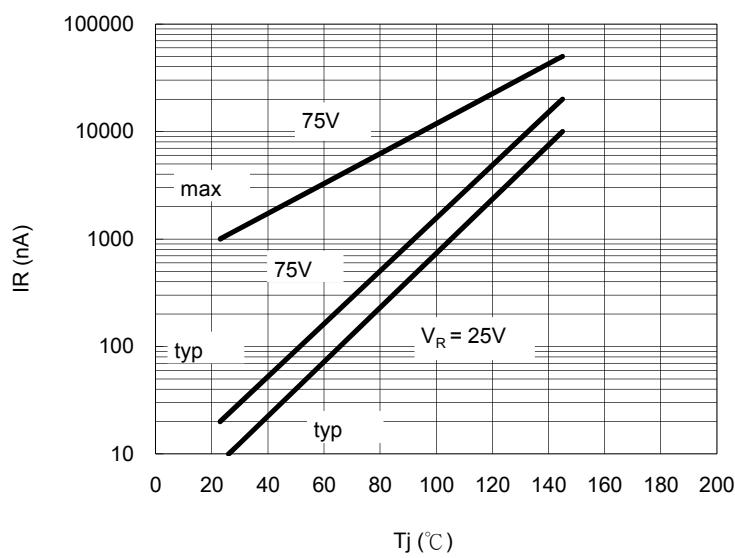
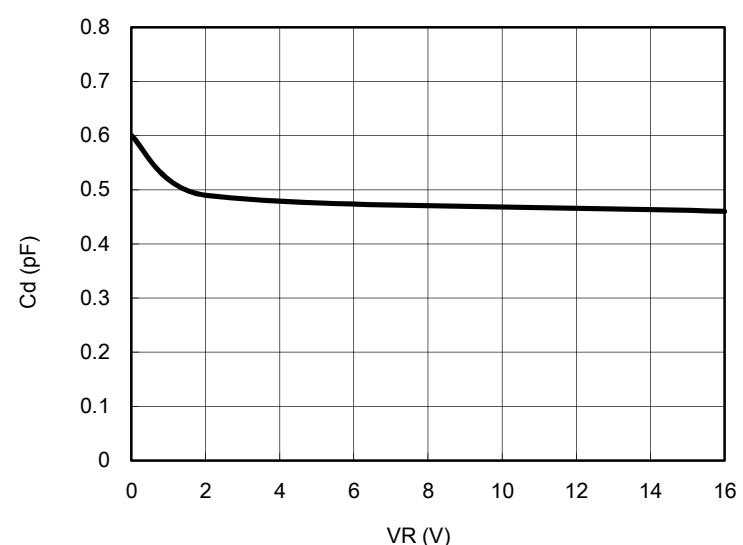
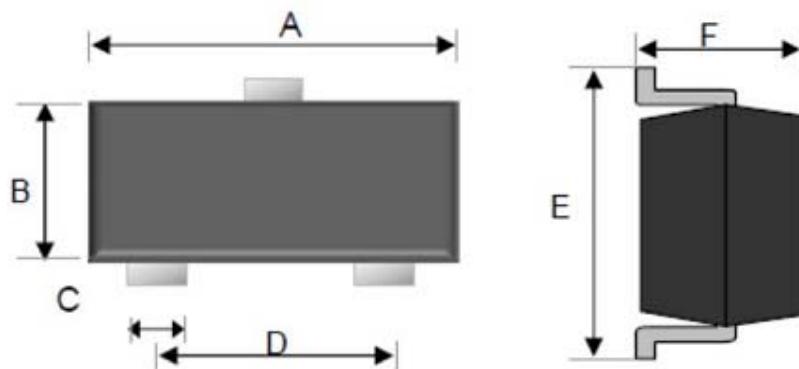


Fig. 5 Typical Capacitance



Small Signal Product

Dimensions

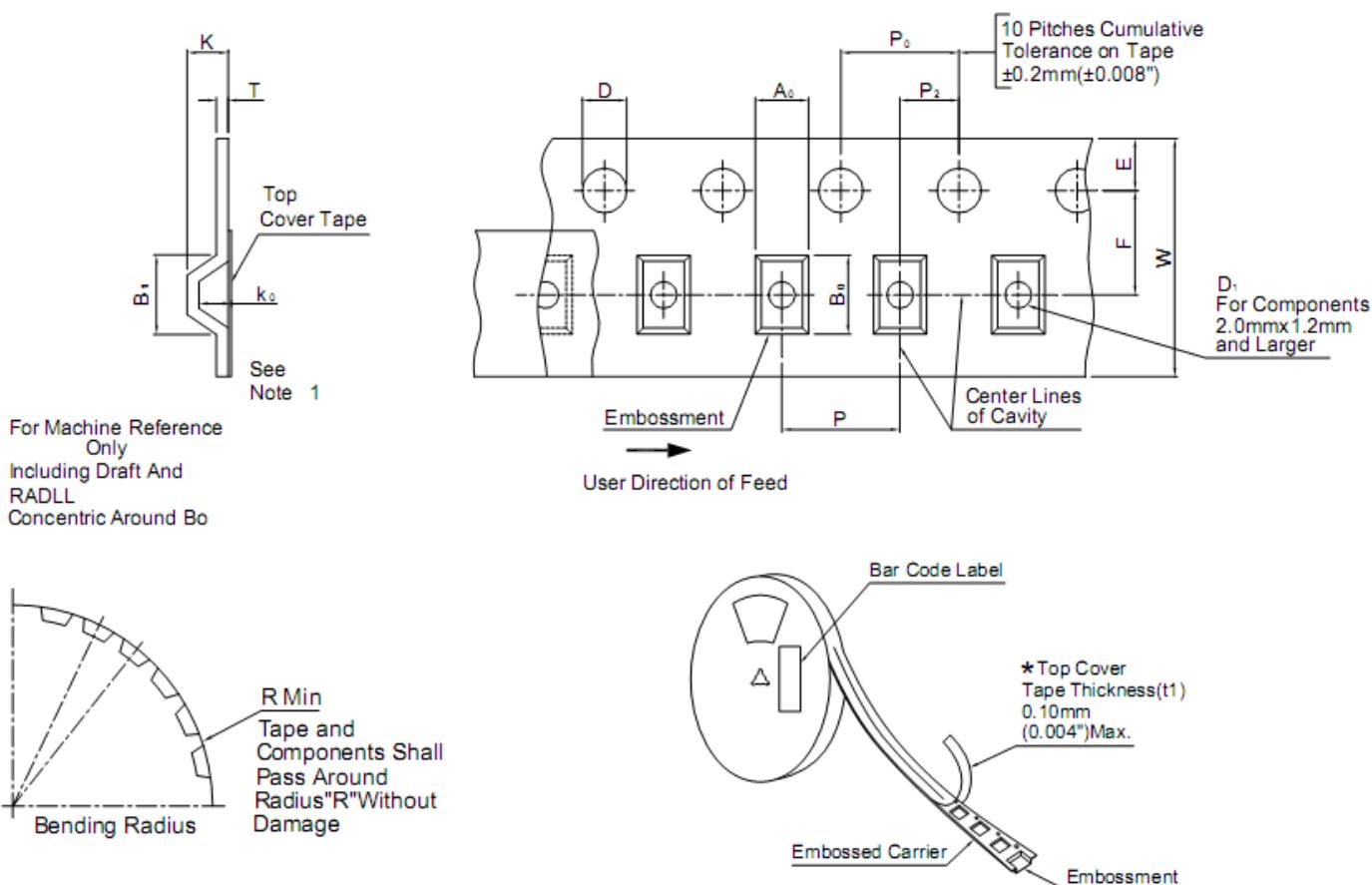


DIM.	Unit(mm)		Unit(inch)	
	Min	Max	Min	Max
A	1.90	2.10	0.075	0.083
B	1.15	1.35	0.045	0.053
C	0.25	0.35	0.010	0.014
D	1.20	1.40	0.047	0.055
E	2.00	2.45	0.079	0.096
F	0.80	1.00	0.031	0.039

Ordering Information

Part No.	Package	Packing	Packing code (Green)	Marking
BAV99W	SOT-323	3K / 7" Reel	RF	RFG

Tape and Reel specification



Tape Size	B1	D	D1	E	F	K	P0	P2	R
	max	+0.1;-0	min	±1.0	±0.05	max	±0.1	±0.1	min
8 mm	4.55	1.5	1	1.75	3.5	2.4	4	2	25

T	W
max	max
0.6	8.3

Unit (mm)

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